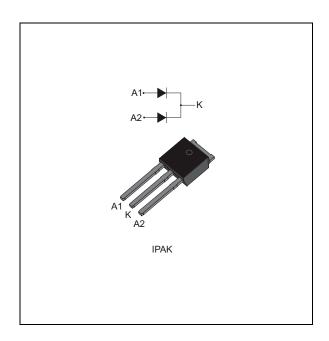


STPS2045CH

Power Schottky rectifier

Datasheet - production data



Description

This device is a dual diode Schottky rectifier, suited to high frequency switch mode power supply.

Packaged in IPAK, this device is intended to be used in notebook, game station and desktop adapters, providing in these applications a good efficiency at both low and high load.

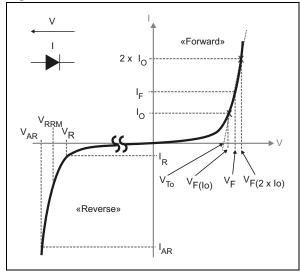
Table 1. Device summary

Symbol	Value
I _{F(AV)}	2 x 10 A
V _{RRM}	45 V
T _j	175 °C
V _{F(typ)}	0.57 V

Features

- · Very small conduction losses
- Avalanche specification
- Low forward voltage drop
- High frequency operation
- ECOPACK®2 compliant on demand

Figure 1. Electrical characteristics^(a)



a. V_{ARM} and I_{ARM} must respect the reverse safe operating area defined in *Figure 9*. V_{AR} and I_{AR} are pulse measurements ($t_p < 10~\mu s$). V_R , I_R , V_{RRM} and V_F , are static characteristics

October 2014 DocID023045 Rev 2 1/8

Characteristics STPS2045CH

1 Characteristics

Table 2. Absolute ratings (limiting values, at 25 °C unless otherwise stated)

Symbol	Parameter	Value	Unit		
V_{RRM}	Repetitive peak reverse voltage			45	V
I _{F(RMS)}	Forward rms current			20	Α
1	Average forward current, equare ways \$ - 0.5	T _c = 155 °C	Per diode	10	Α
I _{F(AV)}	$F(AV)$ Average forward current, square wave, $\delta = 0.5$		Per package	20	
I _{FSM}	Surge non repetitive forward current	$t_p = 10 \text{ ms sine-v}$	150	Α	
P _{ARM} ⁽¹⁾	Repetitive peak avalanche power	$t_p = 10 \ \mu s, \ T_j = 1$	280	W	
V _{ARM} ⁽²⁾	Maximum repetitive peak avalanche voltage	$t_p < 10 \ \mu s, T_j < 1$	60	V	
V _{ASM} ⁽²⁾	Maximum single-pulse peak avalanche voltage $t_p < 10 \mu s$, $T_j < 125 °C$, $I_{AR} < 4.7 A$			60	V
T _{stg}	Storage temperature range			-65 to + 150	°C
Tj	Maximum operating junction temperature ⁽³⁾			175	°C

For pulse time duration derating, please refer to Figure 4. More details regarding the avalanche energy measurements and diode validation in the avalanche are provided in the application notes AN1768 and AN2025.

Table 3. Thermal resistance

Symbol	Parameter			Unit
P	Junction to case	Per diode	2.5	
R _{th(j-c)}	Junction to case	Total	1.6	°C/W
R _{th(c)}	Coupling		0.7	

When the diodes 1 and 2 are used simultaneously:

 ΔT_j (diode 1) = P(diode1) x $R_{th(j-c)}$ (Per diode) + P(diode 2) x $R_{th(c)}$

Table 4. Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I _R ⁽¹⁾	Reverse leakage current	T _j = 25 °C	$V_R = V_{RRM}$			100	μΑ
I _R · / Revi		T _j = 125 °C			7	15	mA
		T _j = 125 °C	I _F = 10 A		0.5	0.57	
V _F ⁽²⁾ Forward voltage	Forward voltage drop	T _j = 25 °C	L = 20 A			0.84	V
		T _j = 125 °C	I _F = 20 A		0.65	0.72	

^{1.} Pulse test: $t_p = 5$ ms, $\delta < 2\%$

^{2.} See Figure 9

^{3.} $\frac{dPtot}{dT_j} < \frac{1}{Rth(j-a)}$ condition to avoid thermal runaway for a diode on its own heatsink

^{2.} Pulse test: t_p = 380 μ s, δ < 2%

STPS2045CH Characteristics

To evaluate the conduction losses use the following equation:

$$P = 0.42 \times I_{F(AV)} + 0.015 I_{F}^{2}(RMS)$$

Figure 2. Average forward power dissipation versus average forward current (per diode)

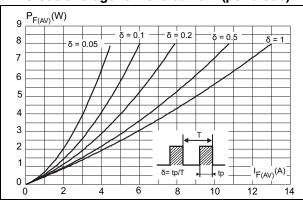


Figure 3. Average forward current versus ambient temperature ($\delta = 0.5$, per diode)

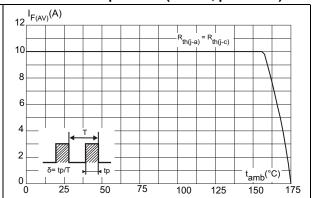
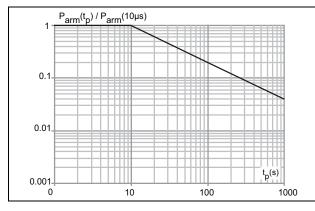


Figure 4. Normalized avalanche power derating versus pulse duration at T_i = 125 °C

Figure 5. Relative variation of thermal impedance junction to case versus pulse duration



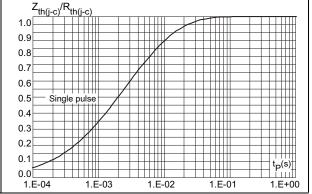
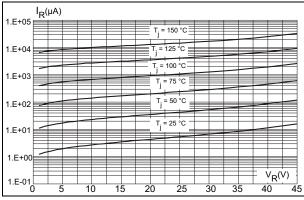
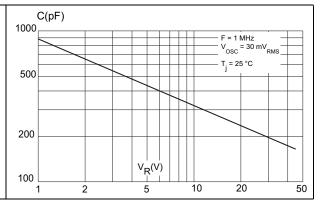


Figure 6. Reverse leakage current versus reverse voltage applied (typical values, per diode)

Figure 7. Junction capacitance versus reverse voltage applied (typical values, per diode)

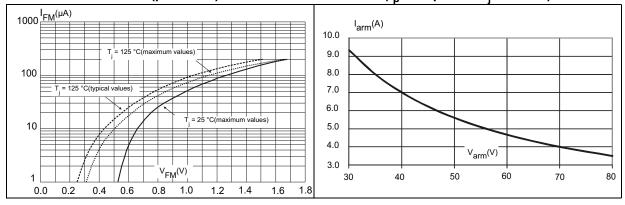




Characteristics STPS2045CH

Figure 8. Forward voltage drop versus forward current (per diode)

Figure 9. Reverse safe operating area $(t_p < 10 \mu s \text{ and } T_j < 125 \text{ °C})$



DocID023045 Rev 2

4/8

2 Package Information

- Epoxy meets UL94, V0
- Lead-free package
- ECOPACK®2 compliant component on demand

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

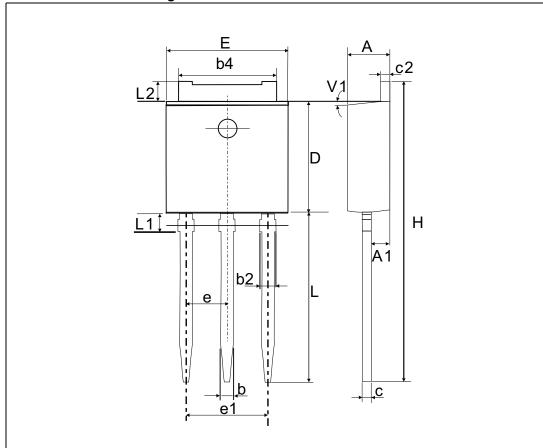


Figure 10. IPAK dimension definitions

Note:

This package drawing may slightly differ from the physical package. However, all the specified dimensions are guaranteed.

Package Information STPS2045CH

Table 5. IPAK dimension values

			Dime	nsions		
Ref.		Millimeters			Inches	
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	2.20		2.40	0.086		0.094
A1	0.90		1.10	0.035		0.043
b	0.64		0.90	0.025		0.035
b2			0.95			0.037
b4	5.20		5.43	0.204		0.213
С	0.45		0.60	0.017		0.023
c2	0.46		0.60	0.018		0.023
D	6		6.20	0.236		0.244
Е	6.40		6.65	0.252		0.262
е		2.28			0.090	
e1	4.40		4.60	0.173		0.181
Н		16.10			0.634	
L	9		9.60	0.354		0.377
L1	0.8		1.20	0.031		0.047
L2		0.80	1.25		0.031	0.049
V1		10°			10°	

3 Ordering information

Table 6. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STPS2045CH	S2045CH	IPAK	0.35 g	75	Tube

4 Revision history

Table 7. Document revision history

Date	Revision	Changes
21-Jun-2012	1	First issue.
09-Oct-2014	2	Updated Table 2 and IPAK package informations.

IMPORTANT NOTICE - PLEASE READ CAREFULLY

STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, enhancements, modifications, and improvements to ST products and/or to this document at any time without notice. Purchasers should obtain the latest relevant information on ST products before placing orders. ST products are sold pursuant to ST's terms and conditions of sale in place at the time of order acknowledgement.

Purchasers are solely responsible for the choice, selection, and use of ST products and ST assumes no liability for application assistance or the design of Purchasers' products.

No license, express or implied, to any intellectual property right is granted by ST herein.

Resale of ST products with provisions different from the information set forth herein shall void any warranty granted by ST for such product.

ST and the ST logo are trademarks of ST. All other product or service names are the property of their respective owners.

Information in this document supersedes and replaces information previously supplied in any prior versions of this document.

© 2014 STMicroelectronics – All rights reserved

4

8/8 DocID023045 Rev 2